



PE3080KS N-Channel Enhancement Mode Power MOSFET

PE3080KS Description

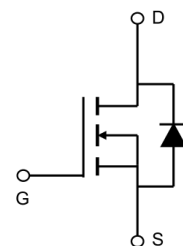
The PE3080KS uses advanced trench technology to provide excellent $R_{DS(ON)}$ and low gate charge. It can be used in a wide variety of applications.

PE3080KS General Features

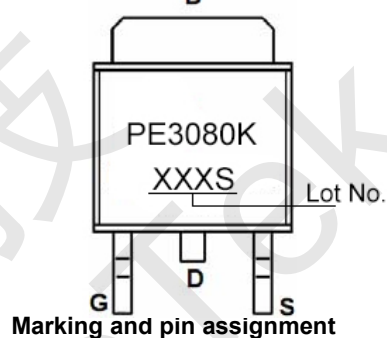
- $V_{DS} = 30V$, $I_D = 80A$
- $R_{DS(ON)} < 5m\Omega$ @ $V_{GS}=10V$
- $R_{DS(ON)} < 9m\Omega$ @ $V_{GS}=4.5V$
- High Power and current handling capability
- Lead free product is acquired
- Surface Mount Package

PE3080KS Application

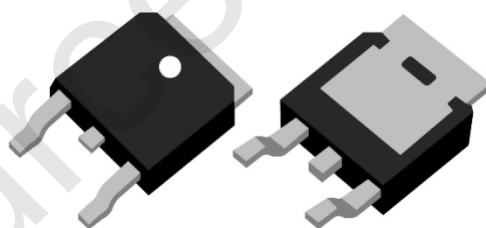
- Battery management
- Motor controller and driver
- PWM applications
- Load switch



Schematic diagram
D



Marking and pin assignment



TO-252-2L

PE3080KS Absolute Maximum Ratings (TC=25°C unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	80	A
Drain Current-Continuous ($T_C=100^\circ C$)	$I_D(T_C=100^\circ C)$	45	A
Pulsed Drain Current (Note 1)	I_{DM}	320	A
Maximum Power Dissipation	P_D	83	W
Single Pulsed Avalanche Energy ($L=0.5mH$)	E_{AS}	306	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	$^\circ C$

PE3080KS Thermal Characteristic

Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.5	$^\circ C/W$
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PE3080KS Electrical Characteristics (TC=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.5	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=30A$	-	4	5	m Ω
		$V_{GS}=4.5V, I_D=20A$	-	7	9	m Ω
Dynamic Characteristics (Note 4)						
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V,$ $F=1.0MHz$	-	2010	-	pF
Output Capacitance	C_{oss}		-	220	-	pF
Reverse Transfer Capacitance (Note 4)	C_{rss}		-	190	-	pF
Switching Characteristics						
Turn-on Delay Time	$t_{d(on)}$	$V_{DS}=15V, I_D=20A,$ $V_{GS}=10V, R_G=3\Omega$	-	20	-	nS
Turn-on Rise Time	t_r		-	17	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	67	-	nS
Turn-Off Fall Time	t_f		-	12	-	nS
Total Gate Charge	Q_g	$V_{DS}=15V, I_D=20A,$ $V_{GS}=10V$	-	36.2	-	nC
Gate-Source Charge	Q_{gs}		-	4.8	-	nC
Gate-Drain Charge	Q_{gd}		-	7.8	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	$V_{GS}=0V, I_S=1A$	-	-	1.2	V
Diode Forward Current (Note 2)	I_S		-	-	80	A
Body Diode Reverse Recovery Time	t_{rr}	$IF=80A, di/dt=100A/\mu s$	-	32	-	nS
Body Diode Reverse Recovery Charge	Q_{rr}		-	12	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to product.



PE3080KS Typical Electrical and Thermal Characteristics

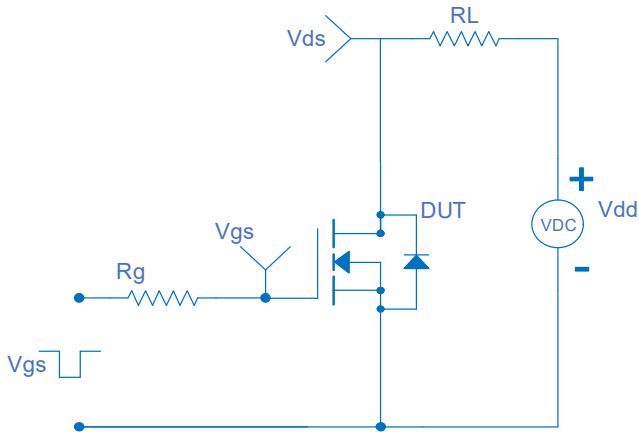


Figure 1 Switching Test Circuit

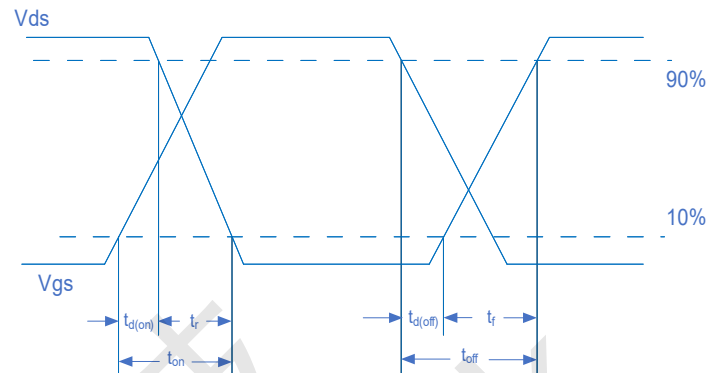


Figure 2 Switching Waveform

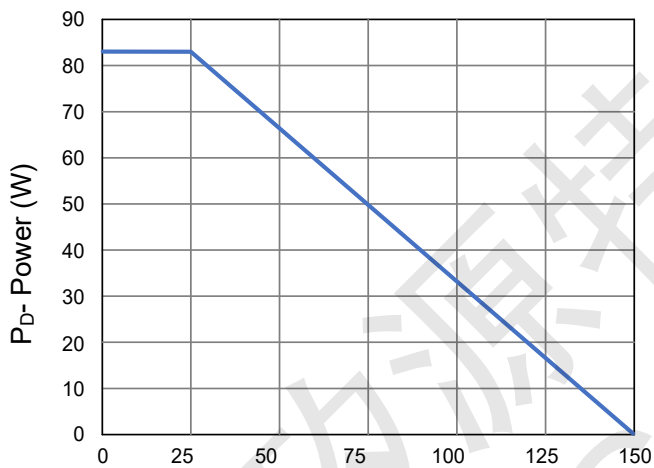


Figure 3 Power De-rating

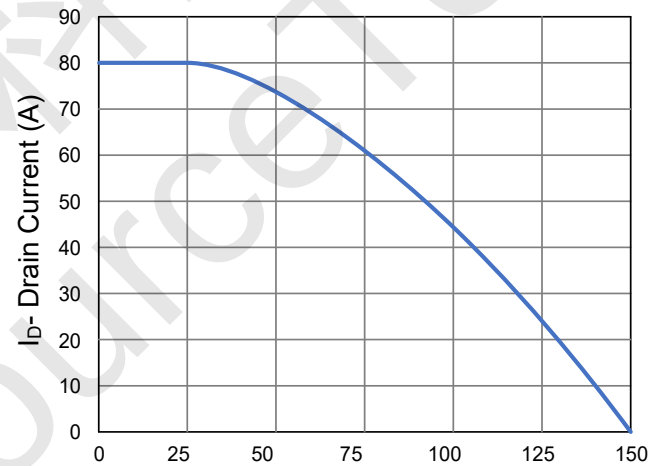


Figure 4 Drain Current

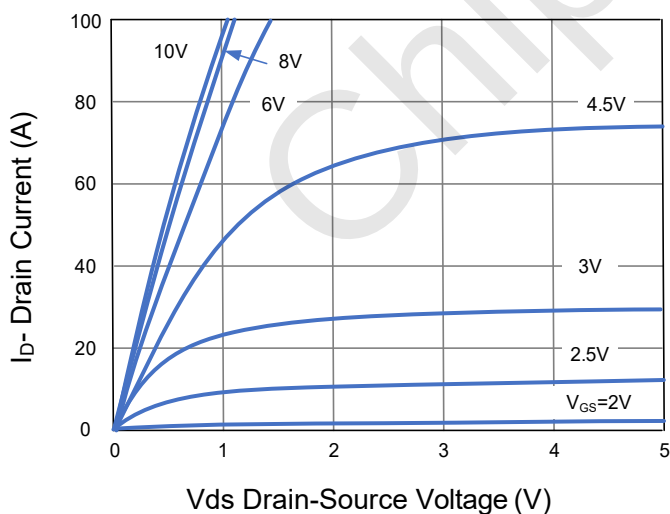


Figure 5 Output Characteristics

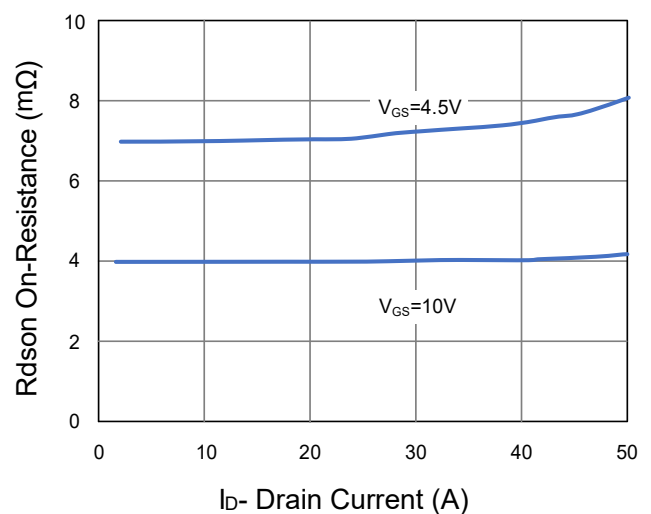


Figure 6 Rdson vs Drain Current

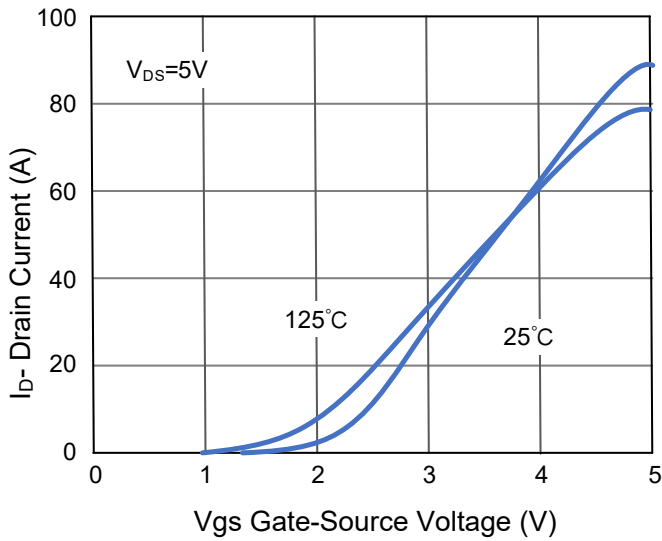


Figure 7 Transfer Characteristics

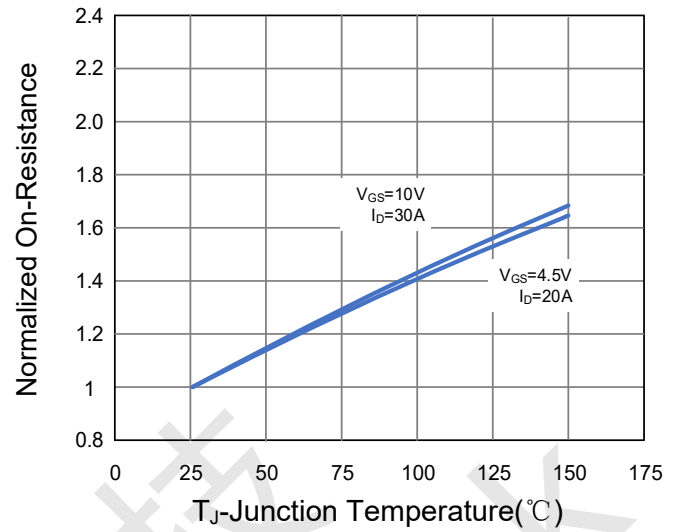


Figure 8 Rdson vs Junction Temperature

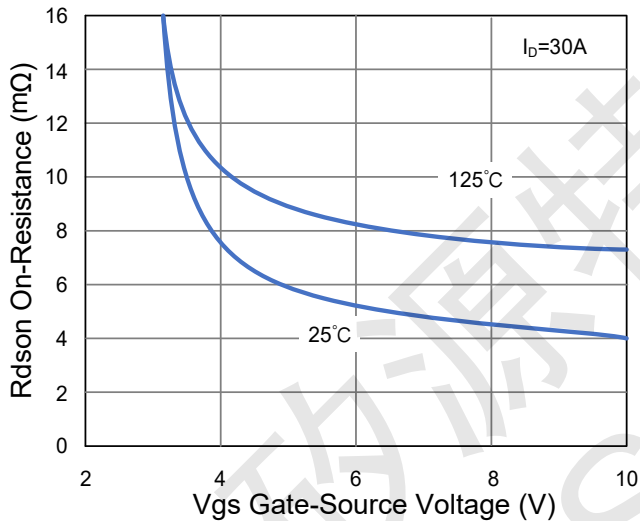


Figure 9 Rdson vs V_GS

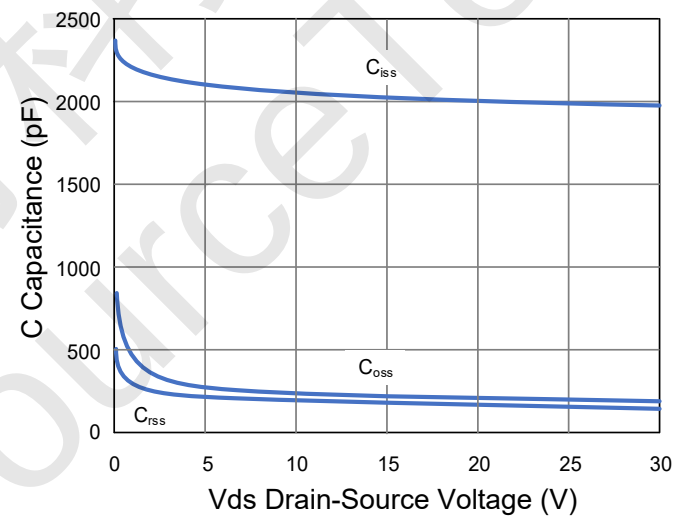


Figure 10 Capacitance vs V_DS

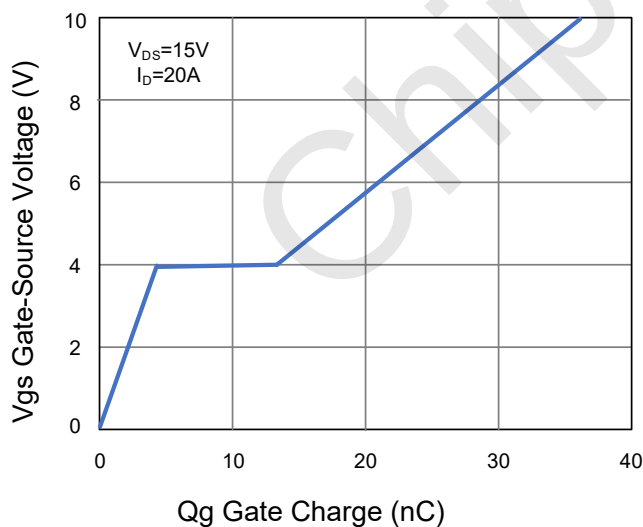


Figure 11 Gate Charge

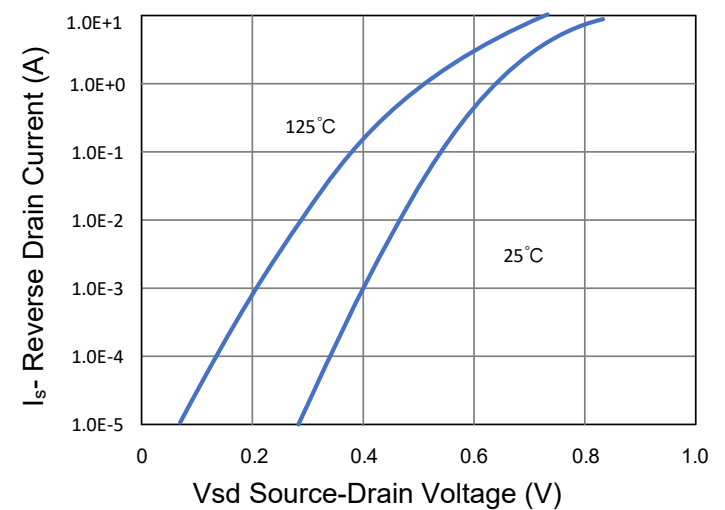


Figure 12 Source- Drain Diode Forward

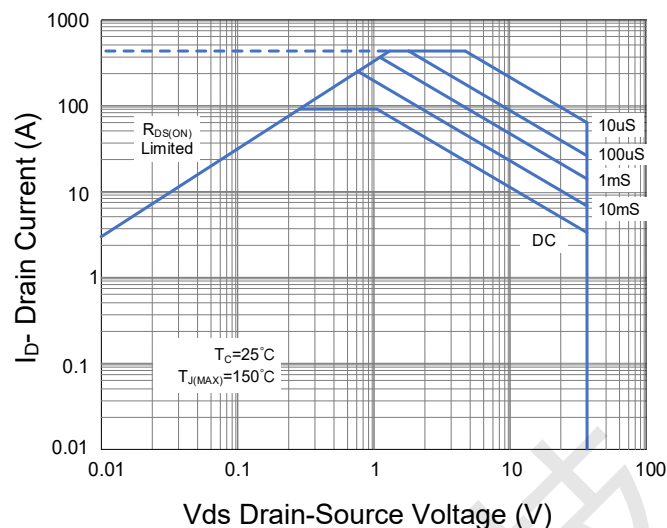


Figure 13 Safe Operation Area

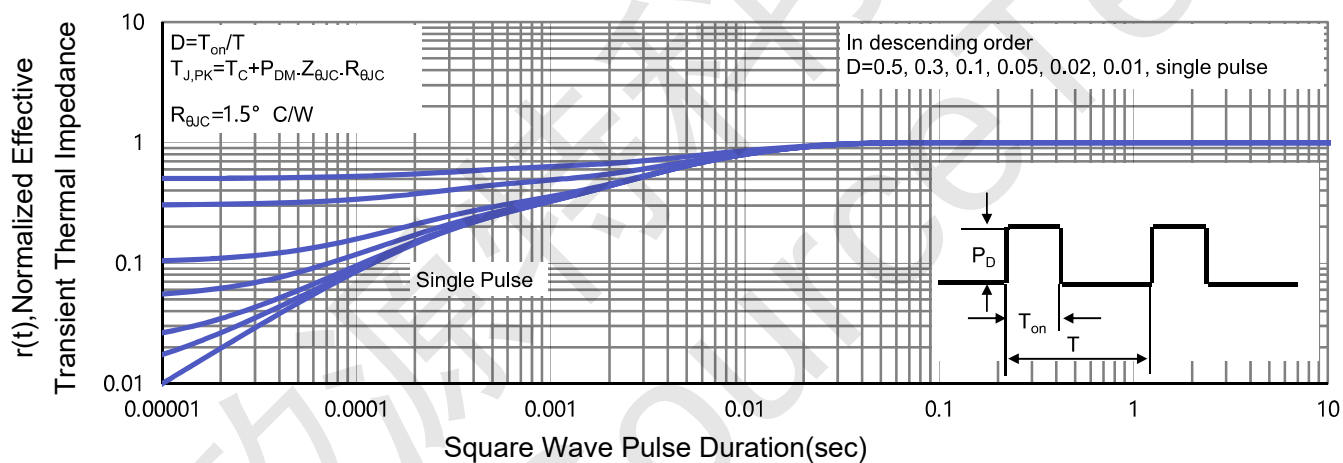
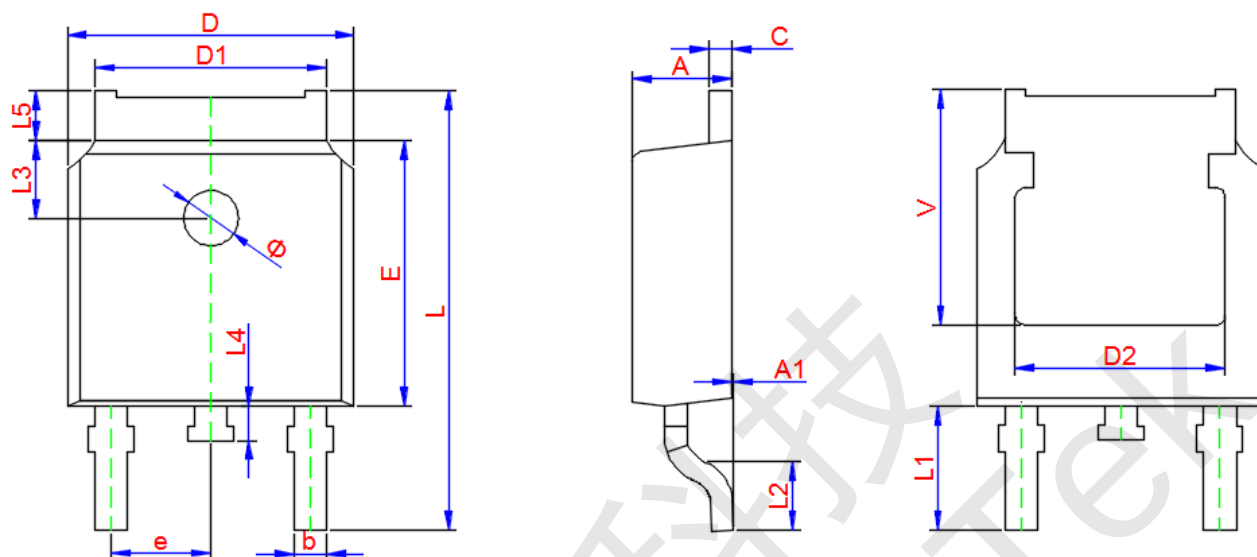


Figure 14 Normalized Maximum Transient Thermal Impedance



PE3080KS TO-252-2L Package Information



Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	2.200	2.300	2.400
A1	0.000	--	0.127
b	0.660	0.760	0.860
D	6.500	6.600	6.700
D1	5.100	5.330	5.460
C	0.450	0.500	0.600
D2	4.830 TYP.		
E	6.000	6.100	6.200
e	2.186	2.286	2.386
L	9.800	10.100	10.400
L1	2.900 TYP.		
L2	1.400	1.500	1.600
L3	1.800 TYP.		
L4	0.600	0.800	1.000
L5	0.900	--	1.250
Φ	1.100.	--	1.300
V	5.350		